PCB123-01 specification

Contact info

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Governing standard

IPC 6012 Class 2

PCB summary

Layers: 4

Surface: ENIG gold (Ni/Au)

Solder mask: Wet film, mask color blue, top and bottom

Silkscreen: White, top and bottom

Electrical test: Yes
Total thickness: 1.6 mm
Min trace width: 100 um
Min spacing: 100 um
Blind/buried vias: No
Drilled hole qty: 2350

Min hole size: 0.3mm plated

Tolerance: All holes are +/- 0.1mm

Min annular: 0.15mm Aspect ratio: 5.3

PCB Size: 141.5*176.9mm, including board assembly break-off rails top/ bottom

Paste mask stencil: No stencil from PCB manufacturer

No of boards in panel: 1 (one main board, four smaller break-off modules, break-off rails)

Material: FR4 Standard

Number of boards wanted and delivery

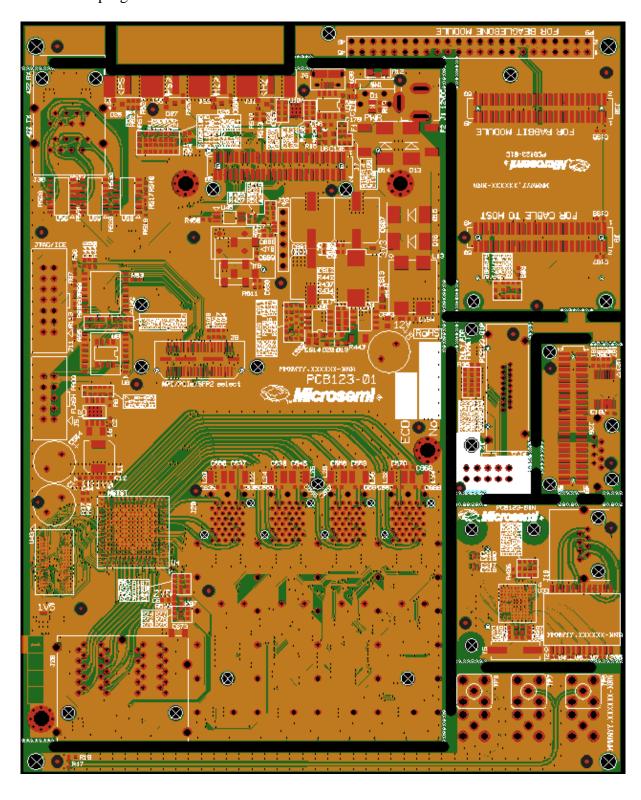
• 42 pcs, with 5 day delivery

Film data

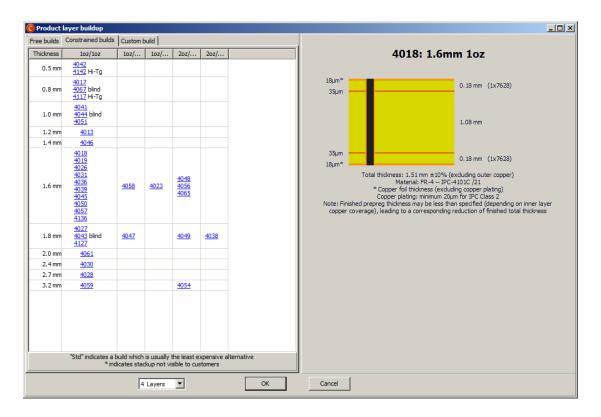
- Extended gerber format
- ODB++ on request

Special

- The design contains a main board as well as four smaller break-off modules, and board assembly break-off rails on the top and bottom edges.
- There are fifteen 2.4mm *non-plated* milled lines specified in the outline layer for board assembly break-off rail and module borders.
- There are three 1.0mm *plated* milled lines specified in the outline layer for a DC power input top right of main board.
- There are four 0.5mm *plated* milled lines specified in the outline layer for a micro-USB connector top right of main board.

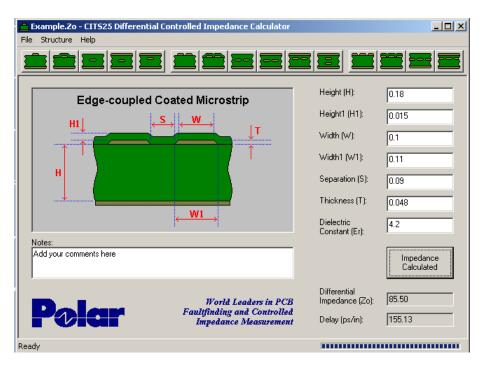


Stackup

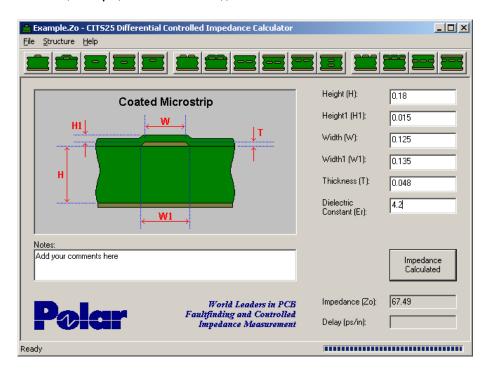


Impedance calculations – informative, boards are *not* impedance controlled in manufacturing

• Differential 100 ohms pairs, outer layers 1 & 4, nominal trace width 100μ (over-etch adjustment -0μ (top-of-trace) +10μ (bottom-of-trace)), nominal separation 100μ (over-etch adjustment -10μ). Our experience is that Polar calculates approx 10 ohms more than our TDR measures, or in other words this geometry results in a measured differential impedance close to 100 ohms.



• DDR3 traces, outer layers 1 & 4. Nominal trace width 125μ (over-etch adjustment -0μ (top-of-trace) +10μ (bottom-of-trace)).



• Regular traces, outer layers 1 & 4. Nominal trace width 100μ (over-etch adjustment -0μ (top-of-trace) $+10\mu$ (bottom-of-trace)).

